

TOSHIBA Infrared LED GaAs Infrared Emitter

TLN233(F)

Lead-Free Product

Infrared LED for Space-Optical-Transmission

Unit: mm

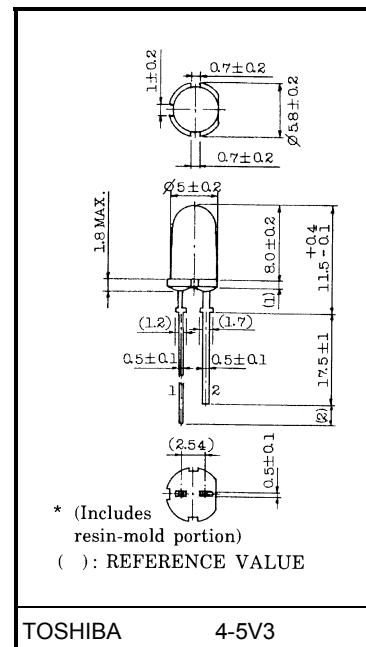
- High radiant intensity: 80 mW/sr (typ.) at $I_F = 50$ mA
- Half-angle value: $\theta_{1/2} = \pm 13^\circ$ (typ.)
- A light source for remote control
- Wireless AV-signal transmission purposes
- High-speed data transmission purposes

Maximum Ratings ($T_a = 25^\circ\text{C}$)

Characteristics	Symbol	Rating	Unit
Forward current	I_F	100	mA
Pulse forward current	I_{FP}	1000 (Note 1)	mA
Power dissipation	P_D	200	mW
Reverse voltage	V_R	4	V
Operating temperature range	T_{opr}	$-25 \sim 85$	$^\circ\text{C}$
Storage temperature range	T_{stg}	$-30 \sim 100$	$^\circ\text{C}$
Soldering temperature (5 s), (Note 2)	T_{sol}	260	$^\circ\text{C}$

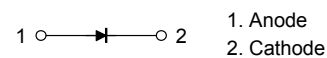
Note 1: $f = 100$ kHz, duty = 1%

Note 2: Soldering must be performed under the stopper.



Weight: 0.3 g (typ.)

Pin Connection



Optical and Electrical Characteristics (Ta = 25°C)

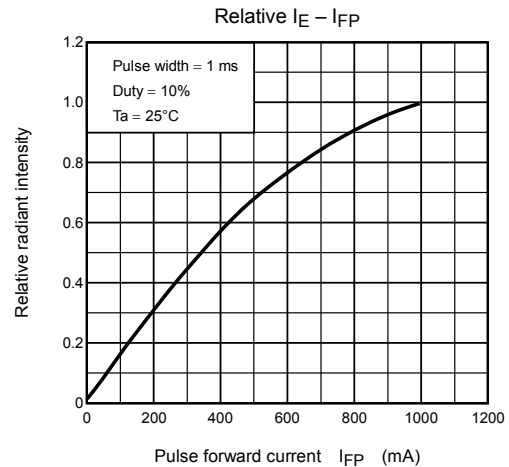
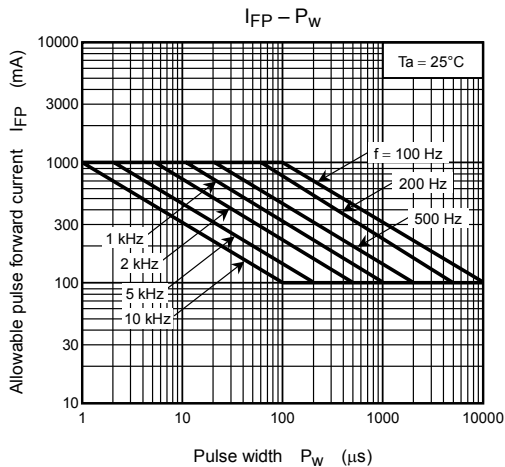
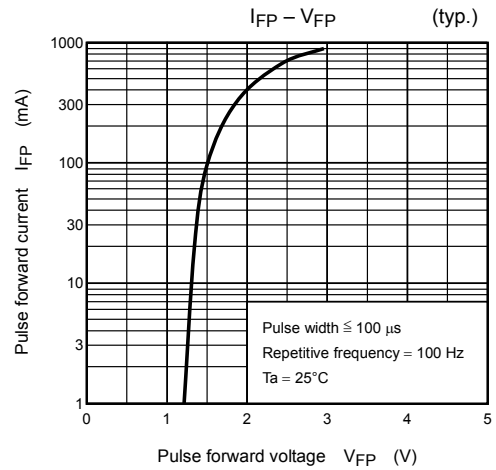
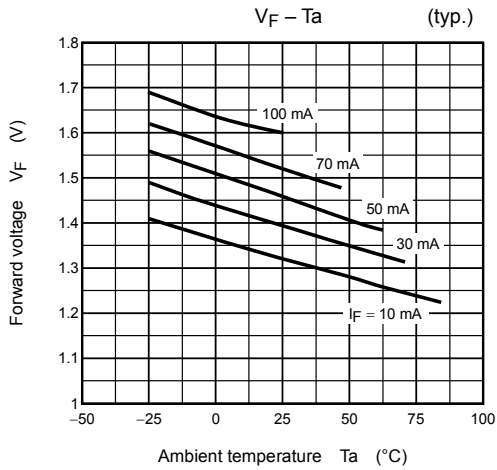
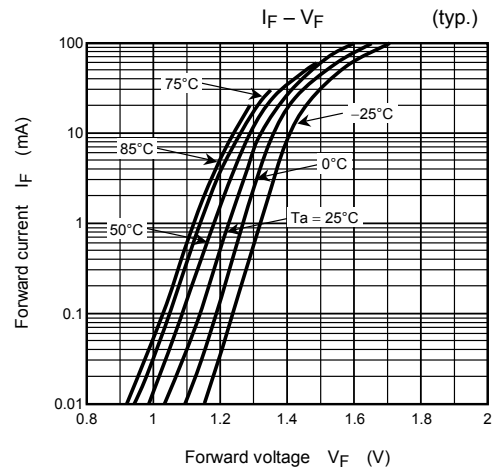
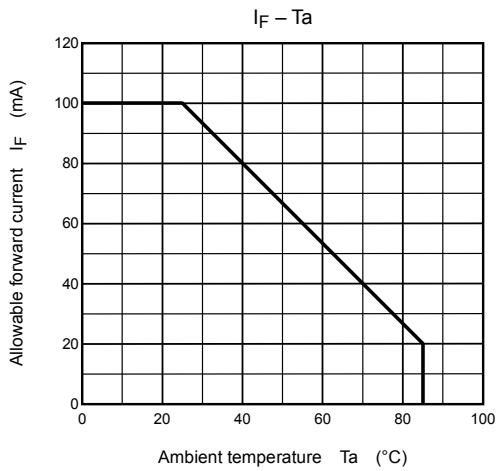
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Forward voltage	V_F	$I_F = 100 \text{ mA}$	—	1.6	2.0	V
Reverse current	I_R	$V_R = 4 \text{ V}$	—	—	60	μA
Radiant intensity	I_E	$I_F = 50 \text{ mA}$	46	80	—	mW/sr
Radiant power	P_O	$I_F = 50 \text{ mA}$	—	30	—	mW
Cut-off frequency	f_c	$I_F = 50 \text{ mA} + 5 \text{ mA}_{P-P}$ (Note 3)	—	15	—	MHz
Peak emission wavelength	λ_P	$I_F = 50 \text{ mA}$	—	870	—	nm
Half-angle value	$\theta_{\frac{1}{2}}$	$I_F = 50 \text{ mA}$	—	± 13	—	°

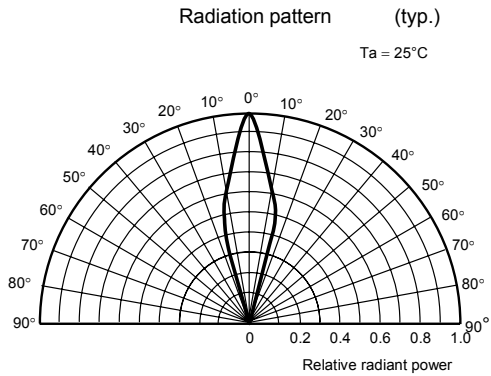
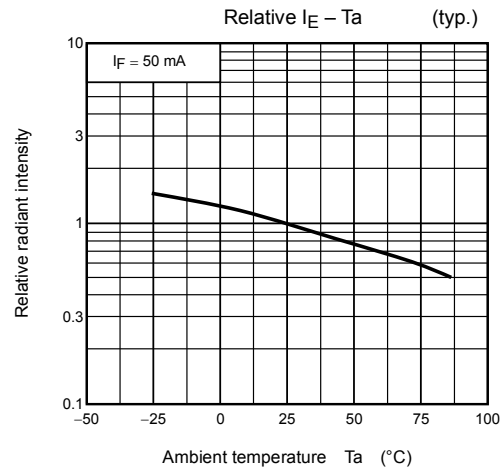
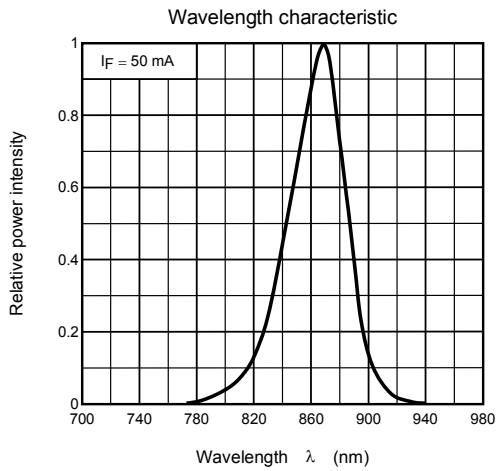
Note 3: This is the frequency when modulation light power decreases by 3 dB from 1 MHz.

Handling Precautions

- Soldering must be performed under the stopper.
- When forming the leads, bend each lead at least 5 mm from the package body. Soldering must be performed after the leads have been formed.
- The radiant intensity decreases over time due to current flowing in the infrared LED. When designing circuits, take into account the change in radiant intensity over time. The change in radiant intensity is equal to the reciprocal of the change in LED infrared optical output:

$$\frac{I_E(t)}{I_E(0)} = \frac{P_O(t)}{P_O(0)}.$$





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- GaAs(Gallium Arsenide) is used in this product. The dust or vapor is harmful to the human body. Do not break, cut, crush or dissolve chemically.